

PHASE CONTROL THYRISTORS

Hockey Puk Version

Features

- Double side cooling
- High surge capability
- High mean current
- Fatigue free

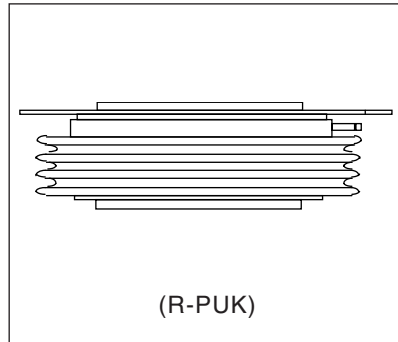
Typical Applications

- DC motor controls
- Controlled DC power supplies
- AC controllers

Major Ratings and Characteristics

| Parameters | ST1900C..R | Units |
|-------------------|--------------|------------------------|
| $I_{T(AV)}$ | 1625 | A |
| | @ T_C | 80 °C |
| $I_{T(AV)}$ | 1940 | A |
| | @ T_{hs} | 55 °C |
| $I_{T(RMS)}$ | 3500 | A |
| | @ T_{hs} | 25 °C |
| I_{TSM} | @ 50Hz | 27500 A |
| | @ 60Hz | 29000 A |
| i^2t | @ 50Hz | 3780 KA ² s |
| | @ 60Hz | 3490 KA ² s |
| V_{DRM}/V_{RRM} | 4500 to 5200 | V |
| t_q | typical | 500 μ s |
| T_J | max. | 125 °C |

1940A



ST1900C..R Series

Bulletin I25197 rev. B 02/00

International
IRF Rectifier

ELECTRICAL SPECIFICATIONS

Voltage Ratings

| Type number | Voltage Code | V_{DRM}/V_{RRM} , max. repetitive peak and off-state voltage V | V_{RSM} , maximum non-repetitive peak voltage V | I_{DRM}/I_{RRM} max. @ $T_C = 125^\circ\text{C}$ mA |
|-------------|--------------|---|--|---|
| ST1900C..R | 45 | 4500 | 4600 | 250 |
| | 46 | 4600 | 4700 | |
| | 48 | 4800 | 4900 | |
| | 50 | 5000 | 5100 | |
| | 52 | 5200 | 5300 | |

On-state Conduction

| Parameter | ST1900C..R | Units | Conditions |
|---|-------------|-------------------|--|
| $I_{T(AV)}$ Max. average on-state current @ Case temperature | 1625 (1030) | A | 180° conduction, half sine wave double side (single side [anode side]) cooled |
| | 80 | °C | |
| $I_{T(AV)}$ Max. average on-state current @ Heatsink temperature | 1940 (800) | A | |
| | 55 (85) | °C | |
| $I_{T(RMS)}$ Max. RMS on-state current | 3500 | A | DC @ 25°C heatsink temperature double side cooled |
| I_{TSM} Max. peak, one-cycle non-repetitive surge current | 27500 | A | t = 10ms No voltage reappplied |
| | 29000 | | t = 8.3ms |
| | 22000 | | t = 10ms 50% V_{RRM} reappplied |
| | 23500 | | t = 8.3ms |
| I^2t Maximum I^2t for fusing | 3780 | KA ² s | t = 10ms No voltage reappplied |
| | 3490 | | t = 8.3ms |
| | 2420 | | t = 10ms 50% V_{RRM} reappplied |
| | 2290 | | t = 8.3ms |
| $V_{T(TO)}$ Max. value of threshold voltage | 1.4 | V | $T_J = T_J \text{ max.}$ |
| r_t Max. value of on-state slope resistance | 0.31 | mΩ | $T_J = T_J \text{ max.}$ |
| V_{TM} Max. on-state voltage | 2.1 | V | $I_{pk} = 2900A, T_C = 25^\circ\text{C}$ |
| I_L Typical latching current | 300 | mA | $T_J = 25^\circ\text{C}, V_D = 5V$ |

Switching

| Parameter | ST1900C..R | Units | Conditions |
|---|------------|-------|---|
| di/dt Max. repetitive 50Hz (no repetitive) rate of rise of turned-on current | 150 (300) | A/μs | From 67% V_{DRM} to 1000A gate drive 20V, 10Ω, $t_r = 0.5\mu\text{s}$ to 1A, $T_J = T_J \text{ max.}$ |
| t_d Maximum delay time | 2.5 | μs | Gate drive 30V, 15Ω, $V_d = 67\% V_{DRM}$, $T_J = 25^\circ\text{C}$ Rise time 0.5μs |
| t_q Typical turn-off time | 500 | | $I_T = 1000A, t_p = 1\text{ms}, T_J = T_J \text{ max.}, V_{RM} = 50V,$ $dI_{FR}/dt = 20A/\mu\text{s}, V_{DR} = 67\% V_{DRM}, dV_{DR}/dt = 8V/\mu\text{s}$ linear |

Blocking

| Parameter | ST1900C..R | Units | Conditions |
|--|------------|------------|---|
| dv/dt Maximum linear rate of rise of off-state voltage | 500 | V/ μ s | $T_J = T_J$ max. to 67% rated V_{DRM} |
| I_{RRM} I_{DRM} Max. peak reverse and off-state leakage current | 250 | mA | $T_J = 125^\circ\text{C}$ rated V_{DRM}/V_{RRM} applied |

Triggering

| Parameter | ST1900C..R | Units | Conditions |
|--|------------|-------|---|
| P_{GM} Maximum peak gate power | 150 | W | $t_p = 100\mu\text{s}$ |
| $P_{G(AV)}$ Maximum average gate power | 10 | | |
| I_{GM} Max. peak positive gate current | 30 | A | Anode positive with respect to cathode |
| V_{GM} Max. peak positive gate voltage | 30 | V | Anode positive with respect to cathode |
| $-V_{GM}$ Max. peak negative gate voltage | 0.25 | V | Anode negative with respect to cathode |
| I_{GT} Maximum DC gate current required to trigger | 400 | mA | $T_C = 25^\circ\text{C}$, $V_{DRM} = 5V$ |
| V_{GT} Maximum gate voltage required to trigger | 4 | V | $T_C = 25^\circ\text{C}$, $V_{DRM} = 5V$ |
| V_{GD} DC gate voltage not to trigger | 0.25 | V | $T_C = 125^\circ\text{C}$ Max. gate current/voltage not to trigger is the max. value which will not trigger any unit with rated V_{DRM} anode-to-cathode applied |

Thermal and Mechanical Specification

| Parameter | ST1900C..R | Units | Conditions | |
|--|-----------------|------------------|--|--|
| T_J max. Max. operating temperature | 125 | $^\circ\text{C}$ | On-state (conducting) | |
| T_{stg} Max. storage temperature range | -55 to 125 | | | |
| R_{thJ-C} Thermal resistance, junction to case | 0.019 0.0095 | K/W | DC operation single side cooled DC operation double side cooled | |
| $R_{th(C-h)}$ Thermal resistance, case to heatsink | 0.004 0.002 | K/W | Single side cooled Double side cooled | Clamping force 43KN with mounting compound |
| F Mounting force $\pm 10\%$ | 43000 (4400) | N (Kg) | | |
| wt Approximate weight | 1600 | g | | |
| Case style | (R-PUK) | | See Outline Table | |

ΔR_{thJ-C} Conduction

(The following table shows the increment of thermal resistance R_{thJ-C} when devices operate at different conduction angles than DC)

| Conduction angle | Single side | Double side | Units | Conditions |
|------------------|-------------|-------------|-------|------------------|
| 180 $^\circ$ | 0.0010 | 0.0010 | K/W | $T_J = T_J$ max. |
| 120 $^\circ$ | 0.0017 | 0.0017 | | |
| 60 $^\circ$ | 0.0044 | 0.0044 | | |

ST1900C..R Series

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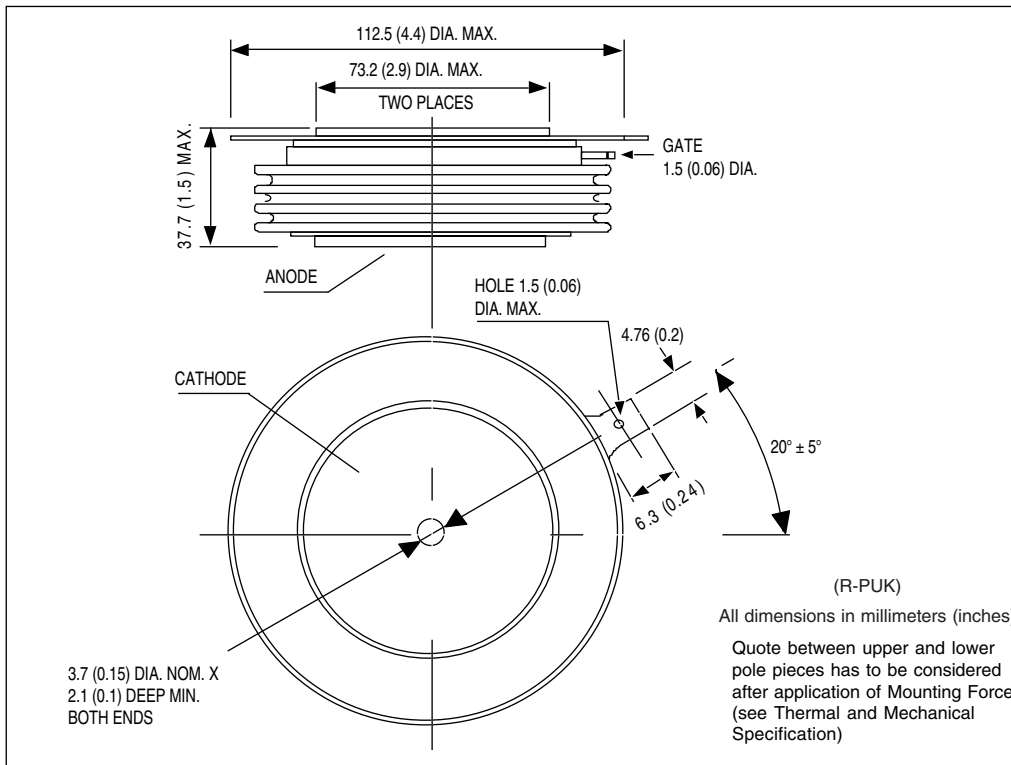
International
IRF Rectifier

Ordering Information Table

| Device Code | | | | | | | |
|-------------|-----|---|---|----|---|---|---|
| ST | 190 | 0 | C | 52 | R | 1 | |
| ① | ② | ③ | ④ | ⑤ | ⑥ | ⑦ | ⑧ |

- 1** - Thyristor
- 2** - Essential part number
- 3** - 0 = Converter grade
- 4** - C = Ceramic Puk
- 5** - Voltage code: Code x 100 = V_{RRM} (See Voltage Rating Table)
- 6** - R = Puk Case
- 7** - 0 = Eyelet terminals (Gate and Auxiliary Cathode Unsoldered Leads)
 1 = Fast-on terminals (Gate and Auxiliary Cathode Unsoldered Leads)
 2 = Eyelet terminals (Gate and Auxiliary Cathode Soldered Leads)
 3 = Fast-on terminals (Gate and Auxiliary Cathode Soldered Leads)
- 8** - Critical dv/dt: None = 500V/ μ sec (Standard selection)
 L = 1000V/ μ sec (Special selection)

Outline Table



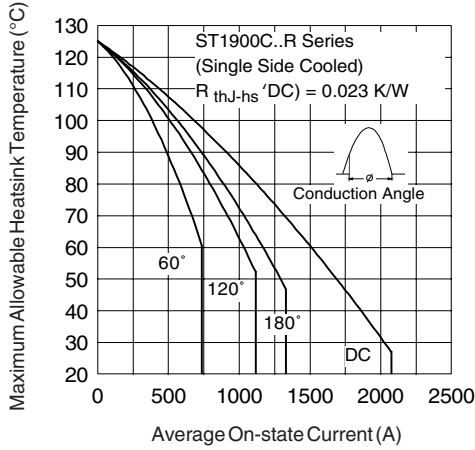


Fig. 1 - Current Ratings Characteristics

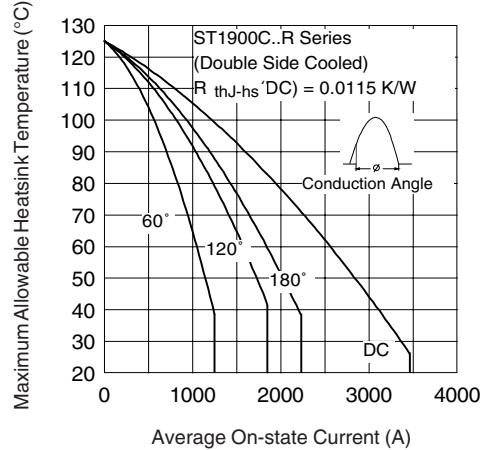


Fig. 2 - Current Ratings Characteristics

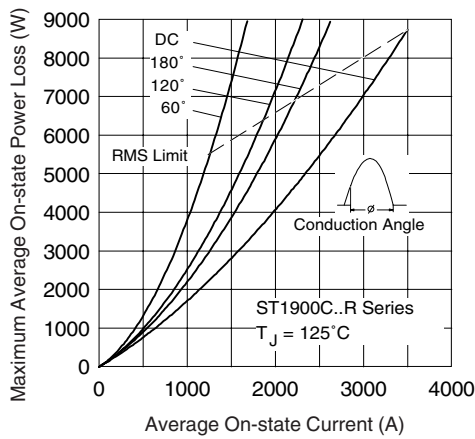


Fig. 3 - On-state Power Loss Characteristics

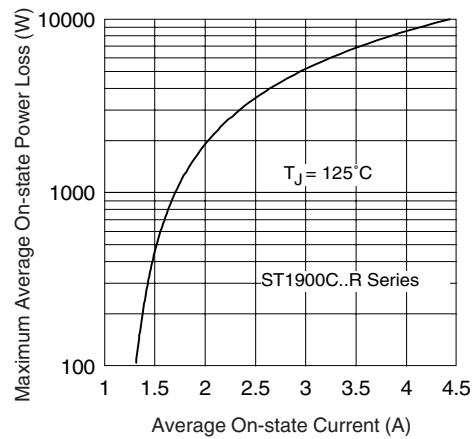


Fig. 4 - On-state Power Loss Characteristics

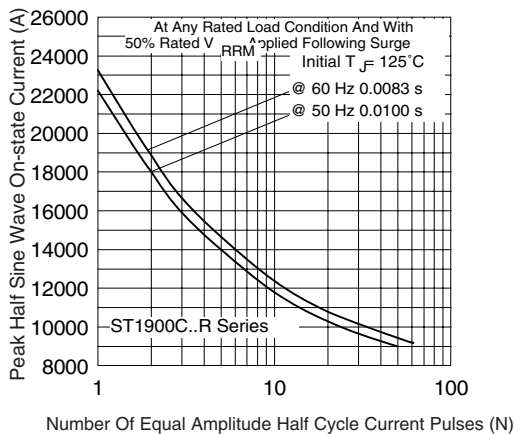


Fig. 5 - Maximum Non-Repetitive Surge Current Single and Double Side Cooled

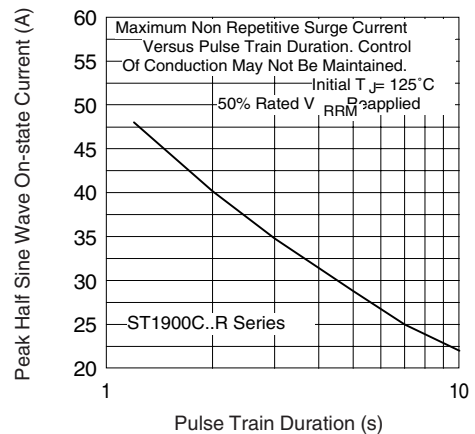


Fig. 6 - Maximum Non-Repetitive Surge Current Single and Double Side Cooled

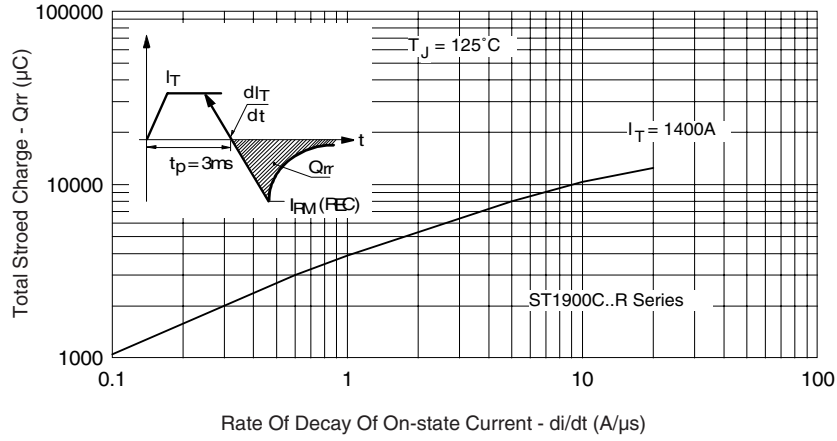


Fig. 7 - Stored Charged

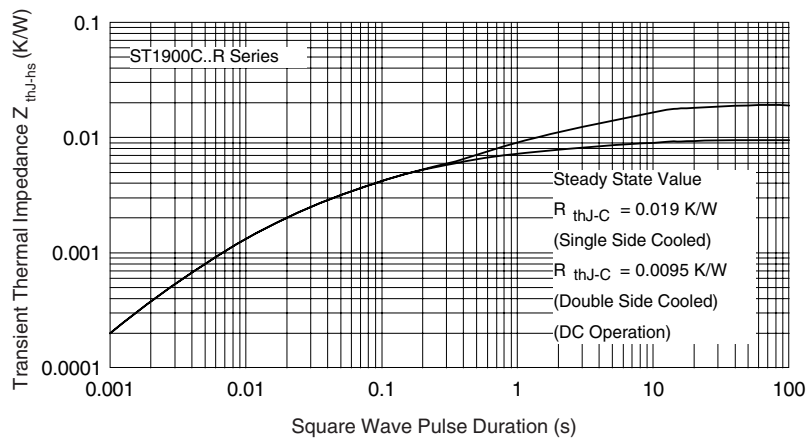


Fig. 10 - Thermal Impedance Z_{thj-hs} Characteristics

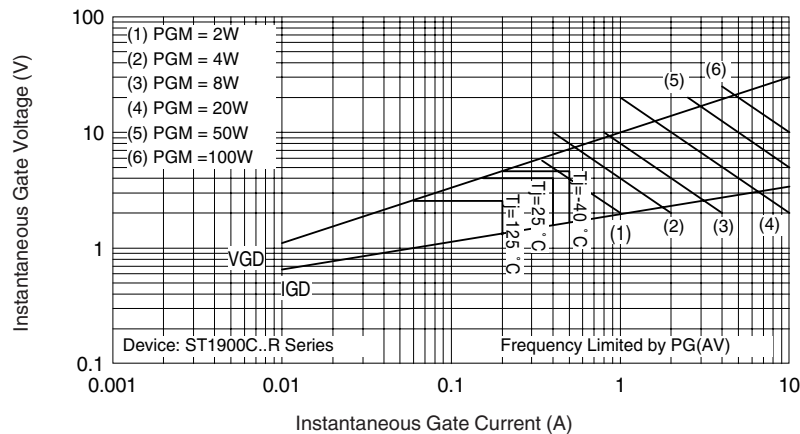


Fig. 11 - Gate Characteristics

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Datasheets for electronics components.